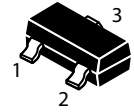
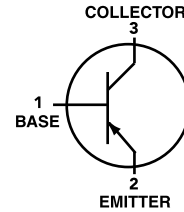


PNP General Purpose Transistors

 Lead(Pb)-Free



SOT-23

MAXIMUM RATINGS(T_a=25°C)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-32	V
Collector-Base Voltage	V _{CBO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous	I _C	-500*	mA
Total Device Dissipation T _A =25°C	P _D	0.2	mW
Junction Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

*P_D MAX. Must not be exceeded.

Device Marking

2SA1036KP=HP , 2SA1036KQ=HQ , 2SA1036KR=HR

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Typ	Max	Unit
Collector-Emitter Breakdown Voltage $I_C = -1\text{mA}, I_E = 0\text{A}$	$V_{(BR)CEO}$	-32	-	-	V
Collector-Base Breakdown Voltage $I_C = -100\mu\text{A}, I_B = 0\text{A}$	$V_{(BR)CBO}$	-40	-	-	V
Emitter-Base Breakdown Voltage $I_E = 100\mu\text{A}, I_C = 0$	$V_{(BR)EBO}$	-5.0	-	-	V
Collector Cutoff Current $V_{CB} = -20\text{V}, I_C = 0\text{A}$	I_{CBO}	-	-	1.0	μA
Emitter Cutoff Current $V_{EB} = -4\text{V}, I_C = 0\text{A}$	I_{EBO}	-	-	1.0	μA

ON CHARACTERISTICS

Collector-Emitter Saturation Voltage $I_C = -100\text{mA}, I_B = -10\text{mA}$	$V_{CE(sat)}$	-	-	-0.4	V
DC Current Transfer Ration $V_{CE} = -3\text{V}, I_C = -10\text{mA}$	h_{FE}	82	-	390	V

SMALL-SIGNAL CHARACTERISTICS

Transition frequency $V_{CE} = -5\text{V}, I_E = 20\text{mA}, f = 100\text{MHz}$	f_T	-	200	-	MHz
Output Capacitance $V_{CB} = -10\text{V}, I_E = 0\text{A}, f = 1.0\text{MHz}$	Cob	-	7	-	pF

CLASSIFICATION h_{FE}

Rank	P	Q	R
Range	82-180	120-270	180-390

Electrical characteristic curves

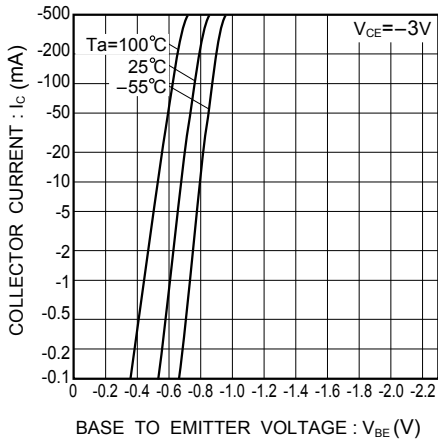


Fig.1 Grounded emitter propagation

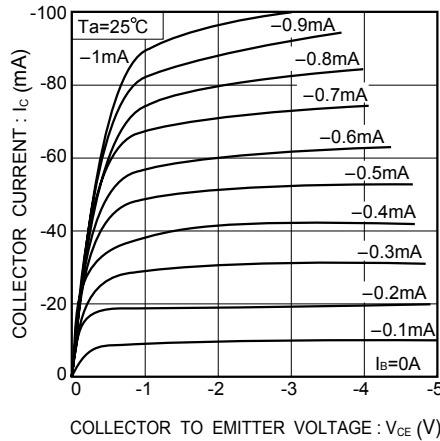


Fig.2 Grounded emitter output characteristics (I)

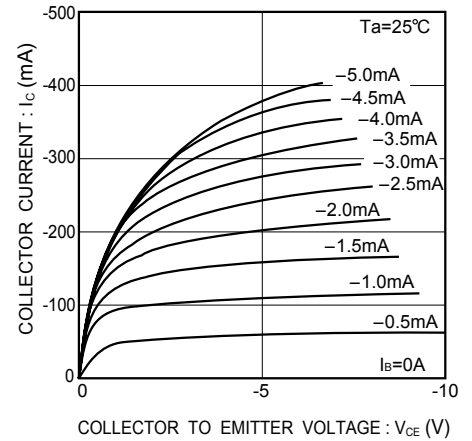


Fig.3 Ground emitter output characteristics (II)

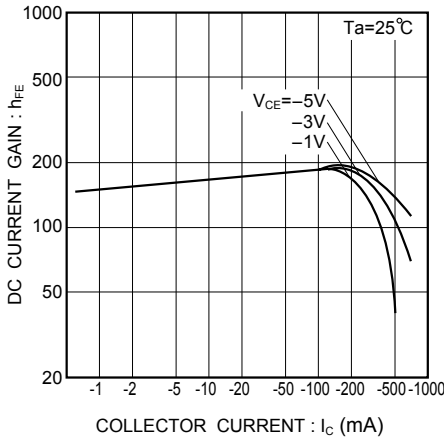


Fig.4 DC current gain vs collector current (I)

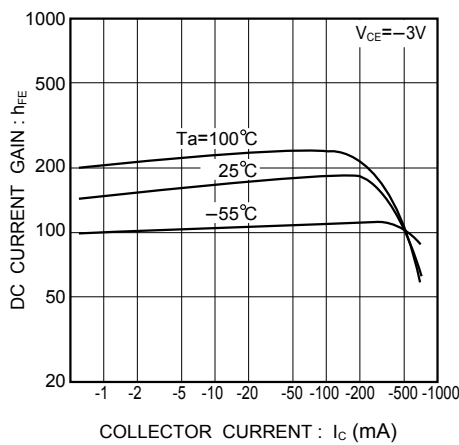


Fig.5 DC current gain vs. collector current (II)

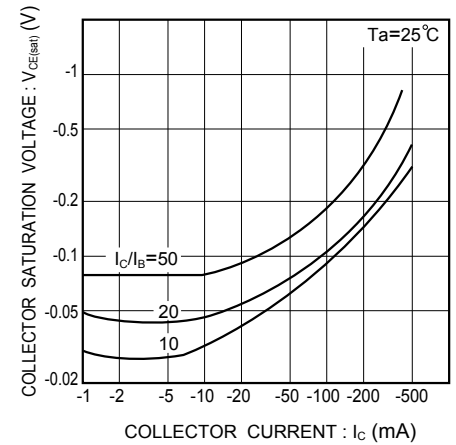


Fig.6 Collector emitter saturation voltage vs. collector current (I)

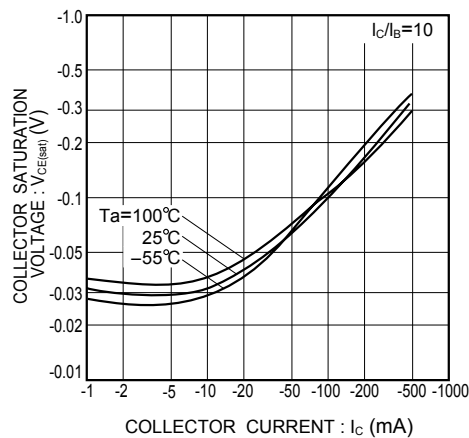


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

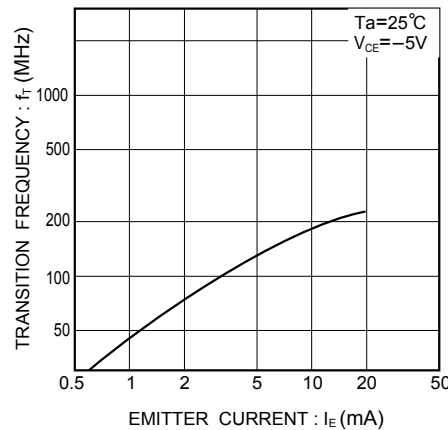


Fig.8 Gain bandwidth product vs. emitter current

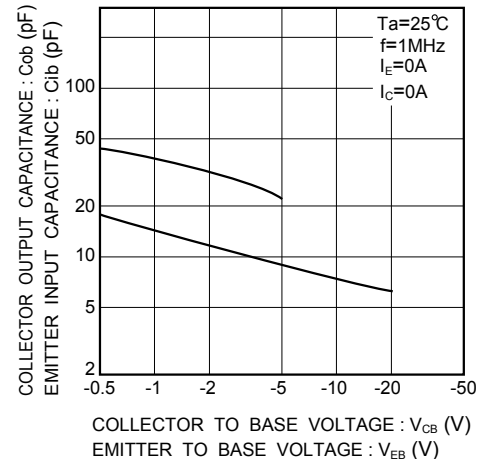
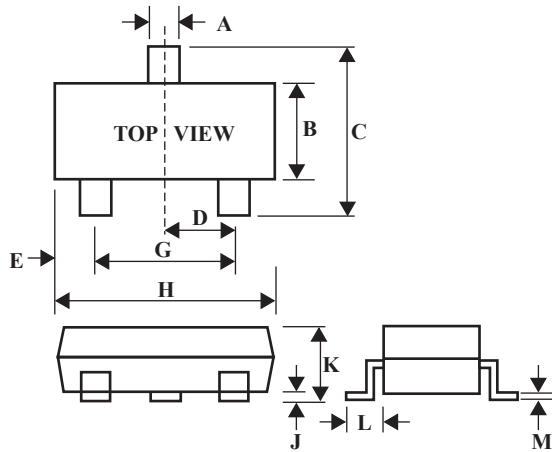


Fig.9 Collector output capacitance vs. collector-base voltage. Emitter input capacitance vs. emitter-base voltage

SOT-23 Outline Dimension



SOT-23		
Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25